



Product Description

The SGA5586Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.

Features

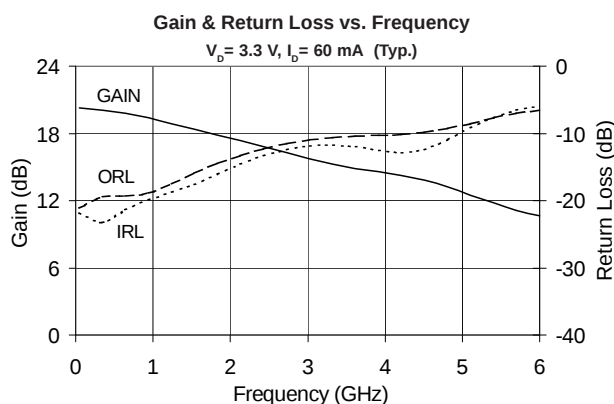
- High Gain: 18.7 dB at 1950MHz
- Cascadable 50 Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Optimum Technology Matching® Applied

- ☐ GaAs HBT
- ☐ GaAs MESFET
- ☐ InGaP HBT
- ☐ SiGe BiCMOS
- ☐ Si BiCMOS
- ☒ SiGe HBT
- ☐ GaAs pHEMT
- ☐ Si CMOS
- ☐ Si BJT
- ☐ GaN HEMT
- ☐ RF MEMS



Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Small Signal Gain		23.1		dB	850MHz
		18.7		dB	1950MHz
		17.3		dB	2400MHz
Output Power at 1dB Compression		18.1		dBm	850MHz
		15.8		dBm	1950MHz
Output Third Intercept Point		31.6		dBm	850MHz
		28.8		dBm	1950MHz
Bandwidth Determined by Return Loss		4000		MHz	>10dB
Input Return Loss		12.2		dB	1950MHz
Output Return Loss		20.7		dB	1950MHz
Noise Figure		2.6		dB	1950MHz
Device Operating Voltage	3.5	3.9	4.2	V	
Device Operating Current	54	60	66	mA	
Thermal Resistance (Junction - Lead)		97		°C/W	

Test Conditions: $V_S = 8\text{ V}$, $I_D = 60\text{ mA}$ Typ., OIP_3 Tone Spacing = 1 MHz, P_{OUT} per tone = 0 dBm, $R_{BIAS} = 68\Omega$, $T_L = 25^\circ\text{C}$, $Z_S = Z_L = 50\Omega$

Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current (I_D)	120	mA
Max Device Voltage (V_D)	6	V
Max RF Input Power	+16	dBm
Max Junction Temp (T_J)	+150	°C
Operating Temp Range (T_L)	-40 to +85	°C
Max Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH, J-I}$$



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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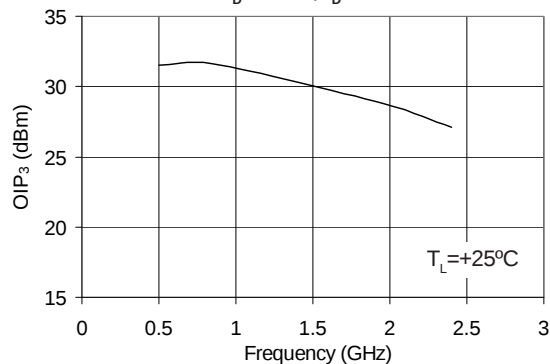
Typical Performance at Key Operating Frequencies

Parameter	Unit	100 MHz	500 MHz	850 MHz	1950 MHz	2400 MHz	3500 MHz
Small Signal Gain	dB	26.0	24.7	23.1	18.7	17.3	14.8
Output Third Order Intercept Point	dBm		31.5	31.6	28.8	27.1	
Output Power at 1dB Compression	dBm		18.3	18.1	15.8	14.4	
Input Return Loss	dB	22.3	13.9	11.8	12.2	12.3	10.6
Output Return Loss	dB	19.8	18.6	18.8	20.7	17.5	14.2
Reverse Isolation	dB	27.7	27.4	27.0	23.4	21.5	17.5
Noise Figure	dB		2.5	2.5	2.6	3.0	

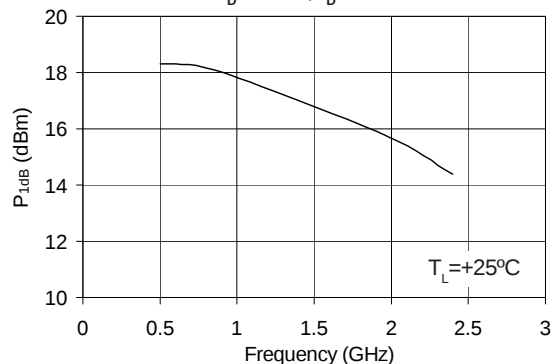
Test Conditions: $V_S = 8V$, $I_D = 60mA$ Typ., OIP_3 Tone Spacing = 1MHz, P_{OUT} per tone = 0dBm, $R_{BIAS} = 75\Omega$, $T_L = 25^\circ C$, $Z_S = Z_L = 50\Omega$

OIP₃ vs. Frequency

$V_D = 3.9V$, $I_D = 60mA$

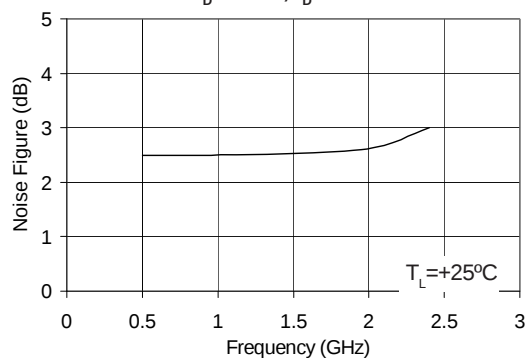
P_{1dB} vs. Frequency

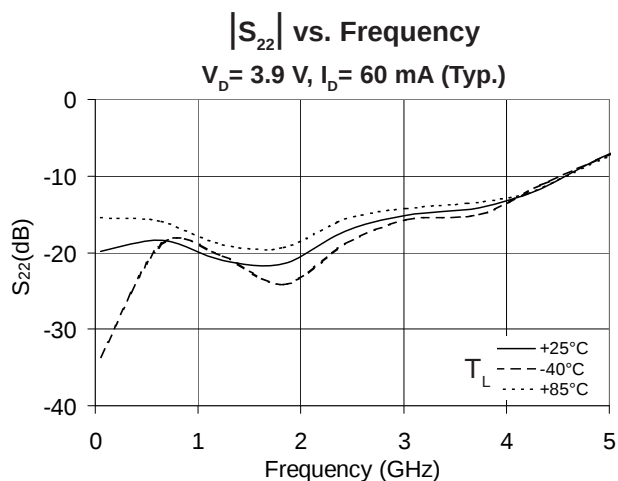
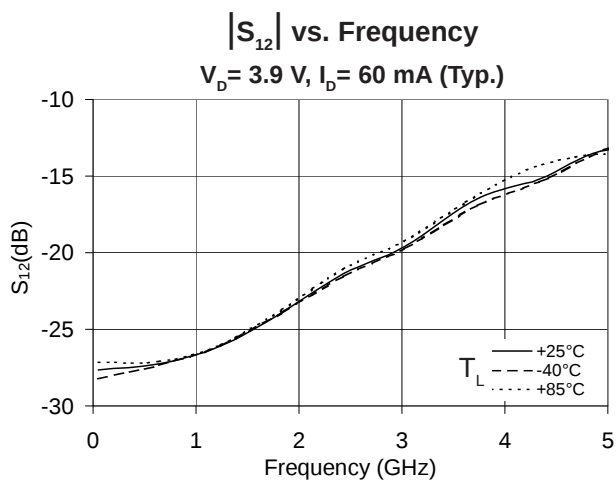
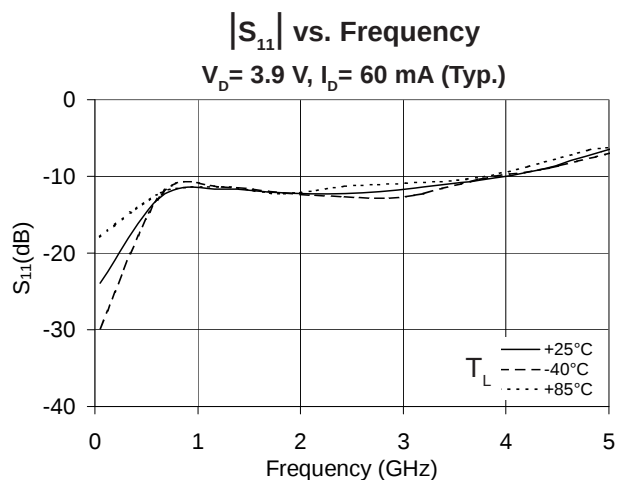
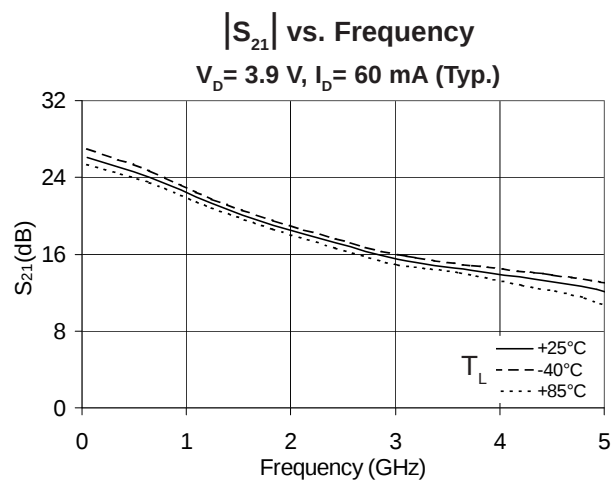
$V_D = 3.9V$, $I_D = 60mA$



Noise Figure vs. Frequency

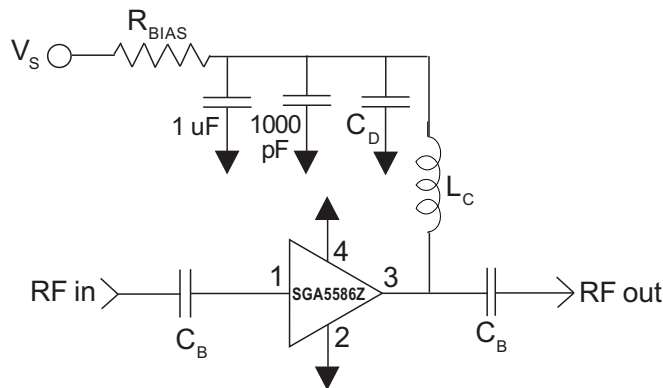
$V_D = 3.9V$, $I_D = 60mA$





Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

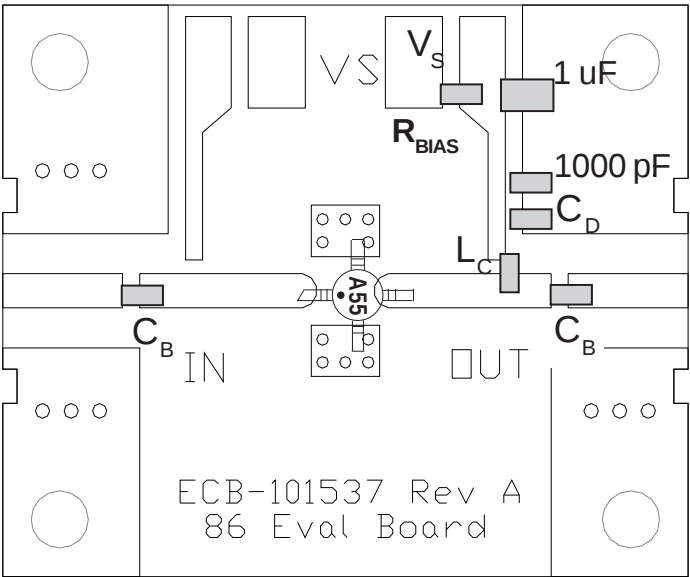
Application Schematic



Reference Designator	Frequency (Mhz)				
	500	850	1950	2400	3500
C _B	220 pF	100 pF	68 pF	56 pF	39 pF
C _D	100 pF	68 pF	22 pF	22 pF	15 pF
L _C	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for I _b =60mA $R_{BIAS} = (V_S - V_D) / I_D$				
Supply Voltage(V _S)	6 V	8 V	10 V	12 V
R _{BIAS}	36 Ω	68 Ω	100Ω	130 Ω
Note: R _{BIAS} provides DC bias stability over temperature.				

Evaluation Board Layout



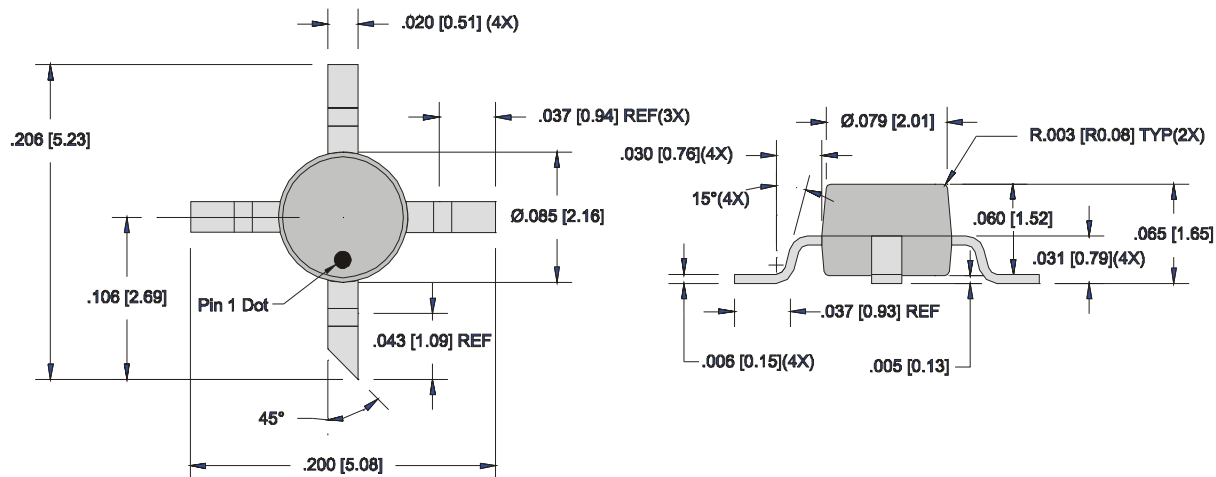
Mounting Instructions

1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
2. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

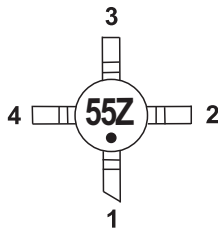
Top view of the device showing dimensions and features. The device is centered on a circular pad with a radius of 0.030 [0.77] (2X). The device is shown for reference only. Dimensions are given in inches [mm] (X).

- 0.120 [3.05] (2X)
- 0.080 [1.52] (2X)
- 0.080 [2.03] (2X)
- 0.040 [1.02] (4X)
- 0.080 [2.29] (2X)
- 0.040 [1.02] (2X)
- 0.025 [0.64] (2X)
- 0.060 [1.52] (2X)
- 0.060 [1.72] (2X)
- 0.030 [0.77] (2X)
- 0.050 [1.27] TYP (2X)
- 0.030 [0.77] Radius (2X)
- 0.020 [0.51] Dia. Ground Via (10X)
- DEVICE CENTERLINE
- DEVICE SHOWN FOR REFERENCE ONLY

Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.



Part Identification



Ordering Information

Ordering Code	Description
SGA5586Z	13" Reel with 3000 pieces
SGA5586ZSQ	Sample bag with 25 pieces
SGA5586ZSR	7" Reel with 100 pieces
SGA5586ZPCK1	850MHz, 8V Operation PCBA with 5-piece sample bag